TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHCT138AF, TC74VHCT138AFN, TC74VHCT138AFT

3 - TO - 8 LINE DECODER

(Note) The JEDEC SOP (FN) is not available in Japan.

The TC74VHCT138 is an advanced high speed CMOS 3 - TO - 8 LINE DECODER fabricated with silicon gate C²MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs ($\overline{Y}0$ - $\overline{Y}7$) will go low.

When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high. G1, $\overline{G}2A$, and $\overline{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

The input voltage are compatible with TTL output voltage.

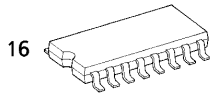
This device may be used as a level converter for interfacing 3.3V to 5V system.

Input protection and output circuit ensure that 0 to 5.5V can be applied to the input and output*1 pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input / output voltages such as battery back up, hot board insertion, etc.

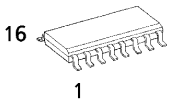
*1 : V_{CC} = 0V

FEATURES :

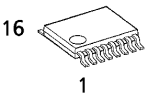
- High Speed ····· t_{pd} = 7.6ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ····· I_{CC} = 4μA(Max.) at Ta = 25°C
- Compatible with TTL outputs ··· V_{IL} = 0.8V (Max.)
  V_{IH} = 2.0V (Min.)
- Power Down Protection is provided on all inputs and outputs
- Balanced Propagation Delays ····· $t_{pLH} \simeq t_{pHL}$
- Pin and Function Compatible with the 74 series (74AC / HC / F / ALS / LS etc.) 138 type.



F (SOP16-P-300-1.27)
Weight : 0.18g (Typ.)

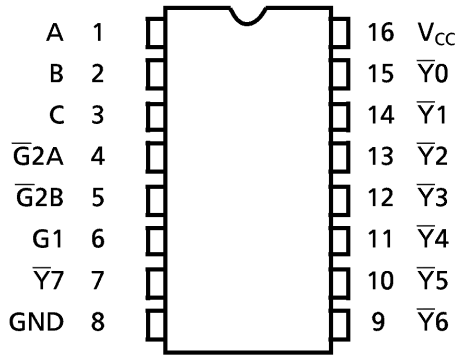


FN (SOL16-P-150-1.27)
Weight : 0.13g (Typ.)



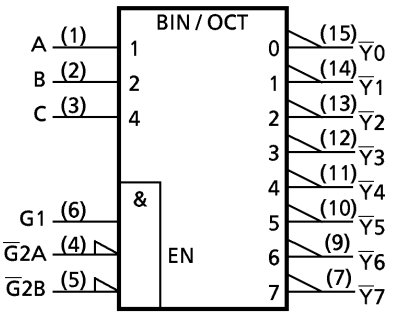
FT (TSSOP16-P-0044-0.65)
Weight : 0.06g (Typ.)

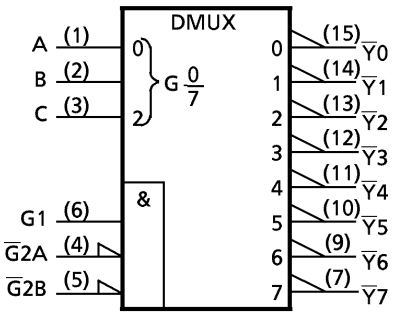
PIN ASSIGNMENT



(TOP VIEW)

IEC LOGIC SYMBOL





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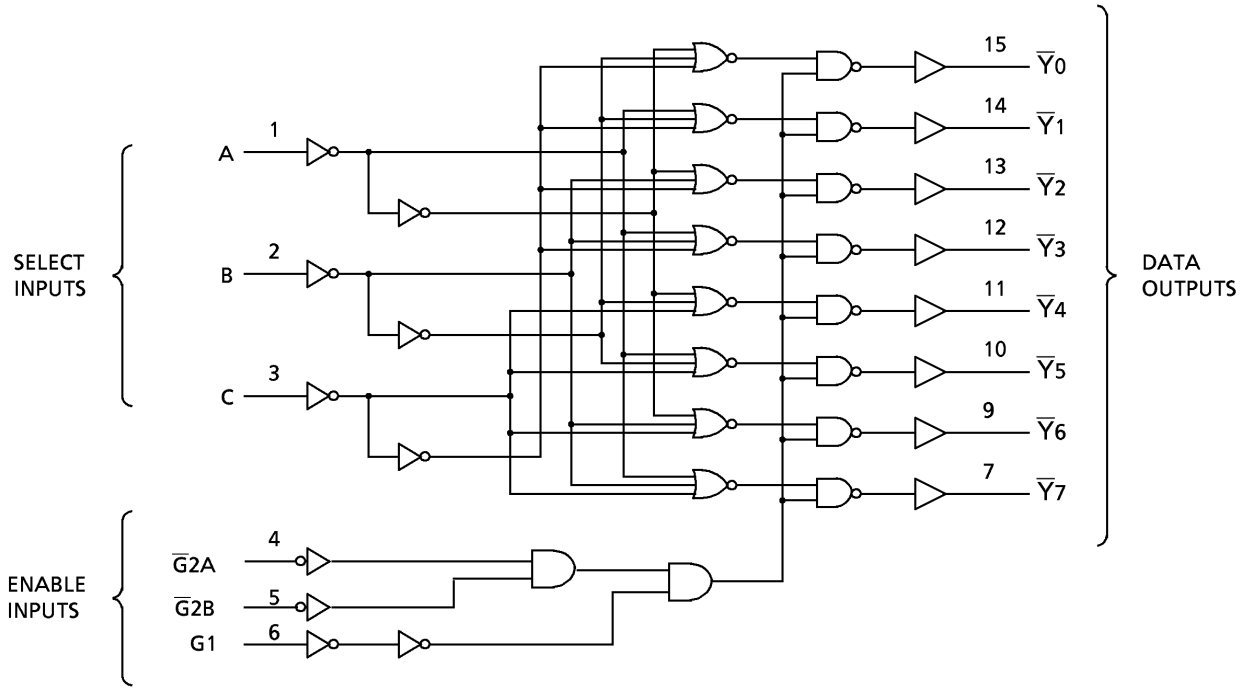
TRUTH TABLE

INPUTS						OUTPUTS								SELECTED OUTPUT
ENABLE			SELECT			$\overline{Y}0$	$\overline{Y}1$	$\overline{Y}2$	$\overline{Y}3$	$\overline{Y}4$	$\overline{Y}5$	$\overline{Y}6$	$\overline{Y}7$	
G1	$\overline{G}2A$	$\overline{G}2B$	C	B	A									
L	X	X	X	X	X	H	H	H	H	H	H	H	H	NONE
X	H	X	X	X	X	H	H	H	H	H	H	H	H	NONE
X	X	H	X	X	X	H	H	H	H	H	H	H	H	NONE
H	L	L	L	L	L	L	H	H	H	H	H	H	H	$\overline{Y}0$
H	L	L	L	L	H	H	L	H	H	H	H	H	H	$\overline{Y}1$
H	L	L	L	H	L	H	H	L	H	H	H	H	H	$\overline{Y}2$
H	L	L	L	H	H	H	H	H	L	H	H	H	H	$\overline{Y}3$
H	L	L	H	L	L	H	H	H	H	L	H	H	H	$\overline{Y}4$
H	L	L	H	L	H	H	H	H	H	H	L	H	H	$\overline{Y}5$
H	L	L	H	H	L	H	H	H	H	H	H	L	H	$\overline{Y}6$
H	L	L	H	H	H	H	H	H	H	H	H	H	L	$\overline{Y}7$

X : Don't Care

SYSTEM DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7.0	V
DC Input Voltage	V_{IN}	−0.5~7.0	V
DC Output Voltage	V_{OUT}	−0.5~7.0 (Note 1)	V
		−0.5~V_{CC}+0.5 (Note 2)	
Input Diode Current	I_{IK}	−20	mA
Output Diode Current	I_{OK}	±20 (Note 3)	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC}/Ground Current	I_{CC}	±75	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	−65~150	°C

(Note 1) V_{CC} = 0V
(Note 2) High or Low State. I_{OUT} absolute maximum rating must be observed.
(Note 3) V_{OUT} < GND, V_{OUT} > V_{CC}

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~5.5 (Note 4)	V
		0~V_{CC} (Note 5)	
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	dt / dV	0~20	ns / V

(Note 4) V_{CC} = 0V
(Note 5) High or Low State.

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITON		V_{CC} (V)	Ta = 25°C			Ta = −40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}			4.5~5.5	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V_{IL}			4.5~5.5	—	—	0.8	—	0.8	V
High - Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50μA	4.5	4.40	4.50	—	4.40	—	V
			I_{OH} = −8mA	4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50μA	4.5	—	0.0	0.1	—	0.1	V
			I_{OL} = 8mA	4.5	—	—	0.36	—	0.44	
Input Leakage Current	I_{IN}	V_{IN} = 5.5V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	4.0	—	40.0	μA
	I_{CCT}	PER INPUT : V_{IN} = 3.4V OTHER INPUT : V_{CC} or GND		5.5	—	—	1.35	—	1.50	mA
Output Leakage Current	I_{OPD}	V_{OUT} = 5.5V		0	—	—	0.5	—	5.0	μA

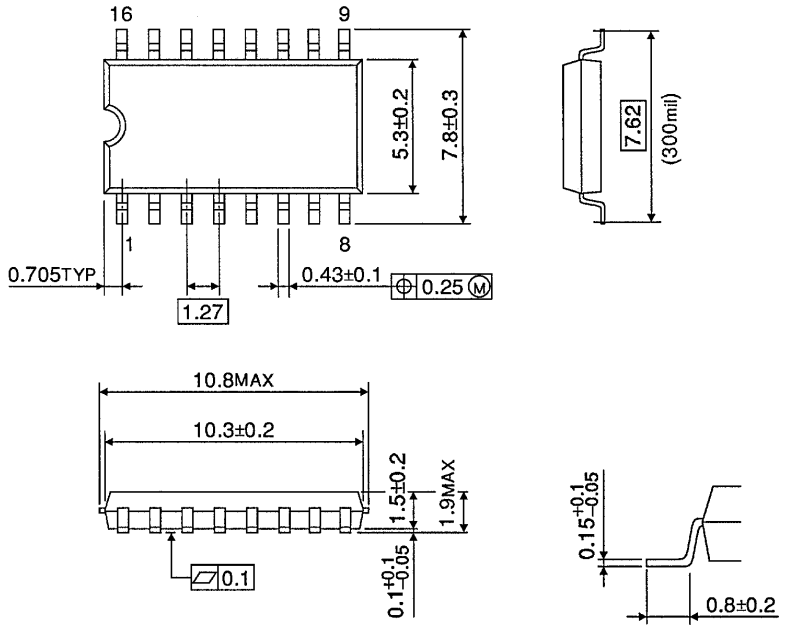
AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION			Ta = 25°C			Ta = −40~85°C		UNIT
			V_{CC} (V)	C_L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (A, B, C − $\overline{Y}$)	t_{pLH} t_{pHL}		5.0 ± 0.5	15	—	7.6	10.4	1.0	12.0	ns
				50	—	8.1	11.4	1.0	13.0	
Propagation Delay Time (G1 − $\overline{Y}$)	t_{pLH} t_{pHL}		5.0 ± 0.5	15	—	6.6	9.1	1.0	10.5	
				50	—	7.1	10.1	1.0	11.5	
Propagation Delay Time ($\overline{G2}$ − $\overline{Y}$)	t_{pLH} t_{pHL}		5.0 ± 0.5	15	—	7.0	9.6	1.0	11.0	MHz
				50	—	7.5	10.6	1.0	12.0	
Input Capacitance	C_{IN}				—	4	10	—	10	pF
Power Dissipation Capacitance	C_{PD}	(Note 1)			—	49	—	—	—	

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

$$I_{CC\,(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

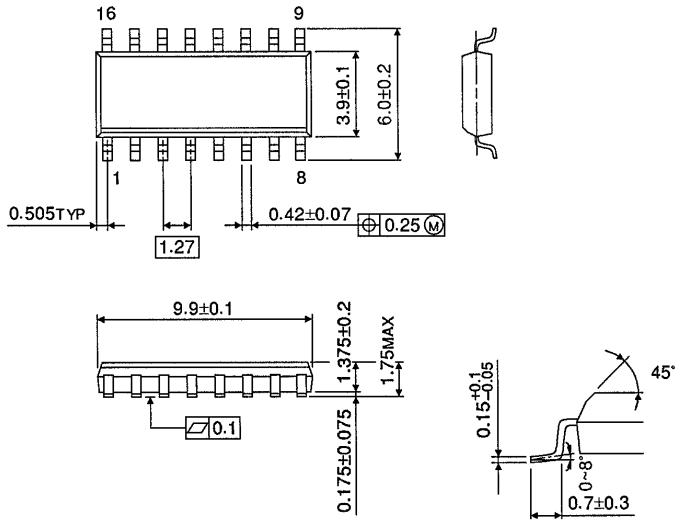
SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27) Unit in mm



Weight : 0.18g (Typ.)

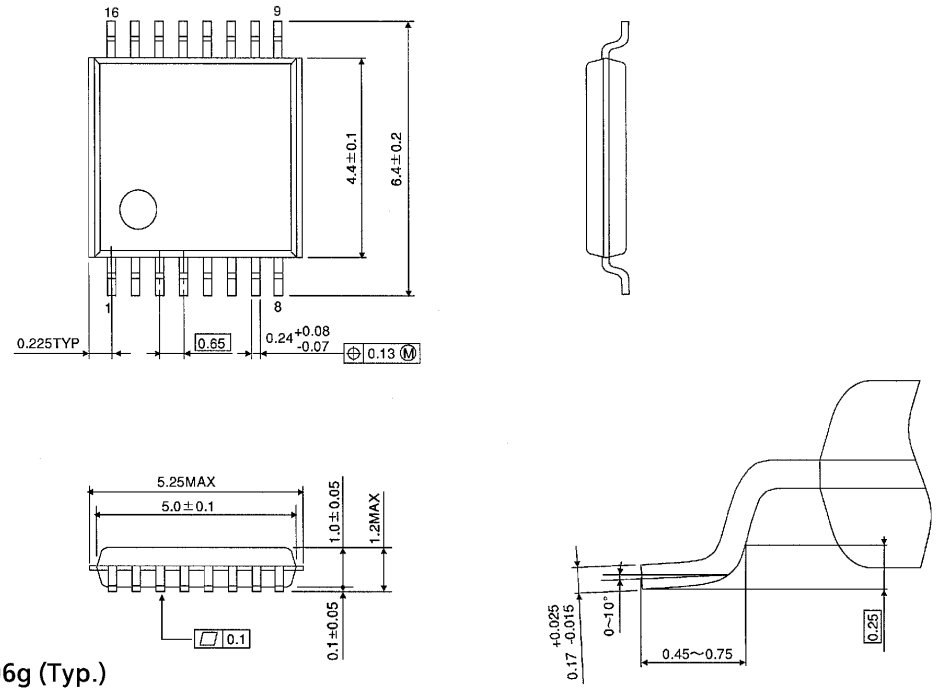
SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150-1.27) Unit in mm

(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)

TSSOP 16PIN PACKAGE DIMENSIONS (TSSOP16-P-0044-0.65) Unit in mm



Weight : 0.06g (Typ.)